



#### 20V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI<sup>®</sup>

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-20V	$8m\Omega$ @ $V_{GS} = -4.5V$	-14A
	$9.8 m\Omega @ V_{GS} = -2.5 V$	-10A
	$13m\Omega$ @ $V_{GS} = -1.8V$	-9.3A
	$17m\Omega$ @ $V_{GS} = -1.5V$	-8.3A

### Description

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(on)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

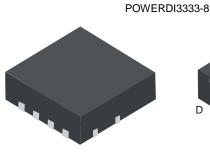
- Load Switch
- **Power Management Functions**

#### **Features**

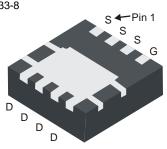
- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

#### **Mechanical Data**

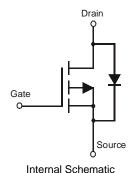
- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (approximate)







**Bottom View** 



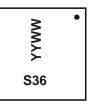
#### Ordering Information (Note 4)

f <del>-</del>		
Part Number	Case	Packaging
DMP2008UFG-7	POWERDI3333-8	2000/Tape & Reel
DMP2008UFG-13	POWERDI3333-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



S36 = Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 11 = 2011) WW = Week code (01 ~ 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	-20	V
Gate-Source Voltage (Note 5)	V <sub>GSS</sub>	±8	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = -4.5V	I <sub>D</sub>	-14 -11 -54	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	-80	Α
Maximum Continuous Body Diode Forward Current (	I <sub>S</sub>	-2.2	Α
Avalanche Current (Note 8)	IAS	-15	Α
Avalanche Energy (Note 8)	E <sub>AS</sub>	-113	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	Б	2.4	W
Total Power Dissipation (Note 6)	$T_C = +25$ °C	P <sub>D</sub>	41	
Thermal Resistance, Junction to Ambient	(Note 5)	Davi	52	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	137	
Thermal Resistance, Junction to Case (Note 6)	Rejc	3.0		
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)	ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.4	l	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		_	1	8	mΩ	$V_{GS} = -4.5V$ , $I_D = -12A$	
Static Drain-Source On-Resistance	5	_	1	9.8		$V_{GS} = -2.5V$ , $I_{D} = -10A$	
Static Diani-Source Off-Resistance	R <sub>DS (ON)</sub>	_	l	13	11152	$V_{GS} = -1.8V$ , $I_{D} = -9.3A$	
		_	1	17		$V_{GS} = -1.5V, I_D = -8.3A$	
Forward Transfer Admittance	Y <sub>fs</sub>	_	42	_	S	$V_{DS} = -5V, I_{D} = -12A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	6909	_		V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	635	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	563	_			
Gate Resistance	R <sub>G</sub>	_	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	$Q_g$	_	72	_			
Total Gate Charge (V <sub>GS</sub> = -2.5V)	$Q_g$	_	40	_	nC	V <sub>DD</sub> = -10V, I <sub>D</sub> = -12A	
Gate-Source Charge	$Q_{gs}$	_	8.6	_	IIC		
Gate-Drain Charge	$Q_{gd}$	_	14.5	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	22	_		V <sub>GS</sub> = -4.5V, V <sub>DD</sub> = -10V,	
Turn-On Rise Time	t <sub>r</sub>	_	33	_			
Turn-Off Delay Time	t <sub>D(off)</sub>	_	291	_	ns	$R_G = 6\Omega$ , $I_D = -12A$	
Turn-Off Fall Time	t <sub>f</sub>	_	124	_			
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	$V_{SD}$	_	-0.7	_	V	$V_{GS} = 0V, I_{S} = -12A$	
Diode i diwald voltage	v sd	_	-0.7	_	V	$V_{GS} = 0V, I_{S} = -2A$	
Reverse Recovery Time (Note 10)	t <sub>rr</sub>	_	25	_	ns	I <sub>F</sub> = -12A, di/dt = 100A/μs	
Reverse Recovery Charge (Note 10)	Qrr	_	15	_	nC	I <sub>F</sub> = -12A, di/dt = 100A/µs	

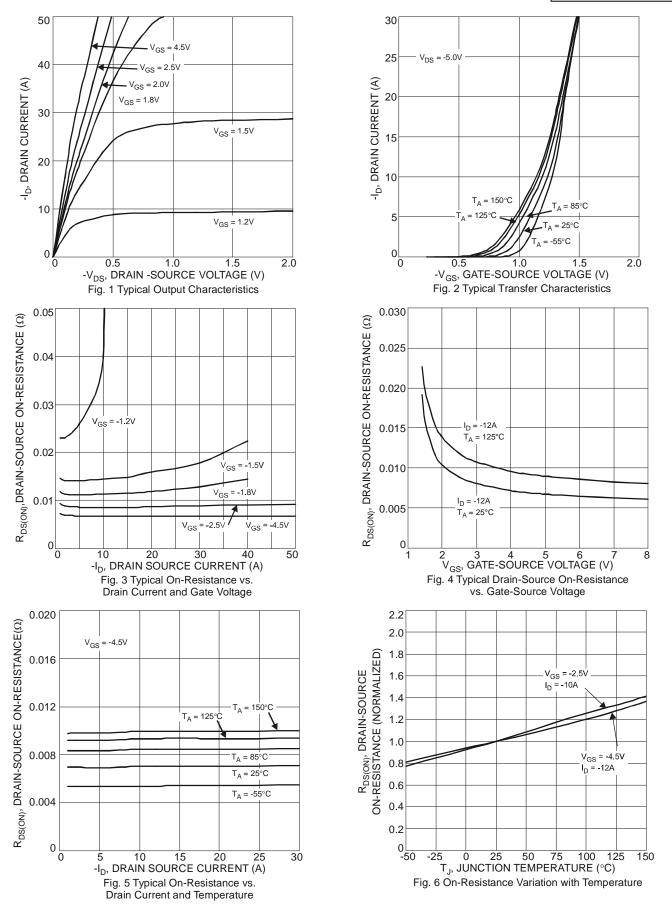
Notes: 5. AEC-Q101  $V_{GS}$  maximum is  $\pm 6.4 V$ .

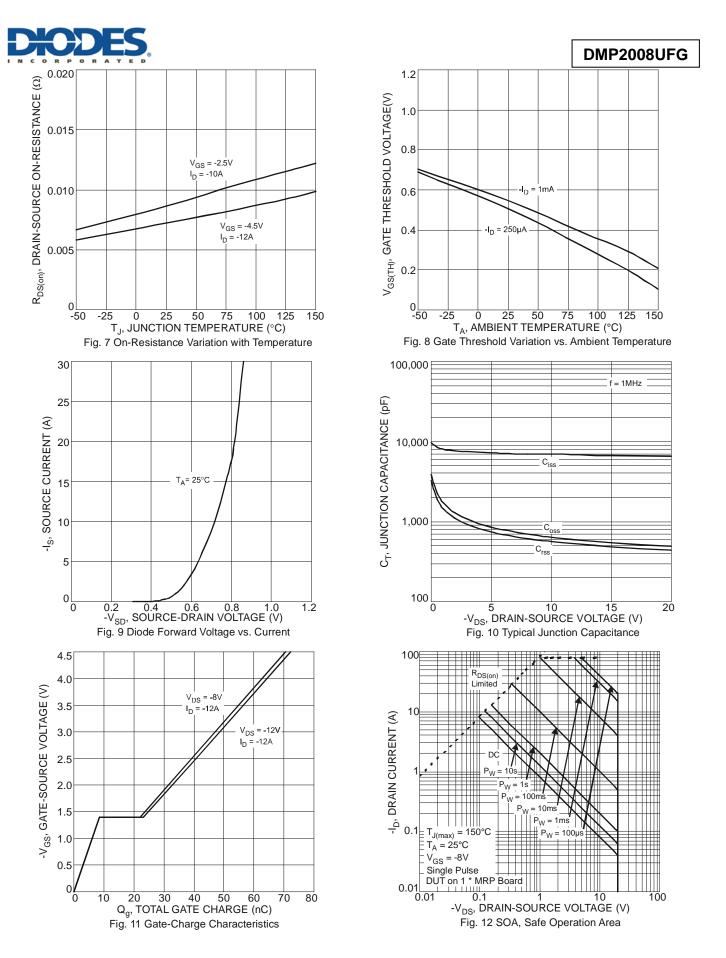
- 6. R<sub>BJA</sub> is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R<sub>BJC</sub> is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 8 .UIS in production with L = 1mH,  $T_J$  = +25°C.
- 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to product testing.

POWERDI is a registered trademark of Diodes Incorporated

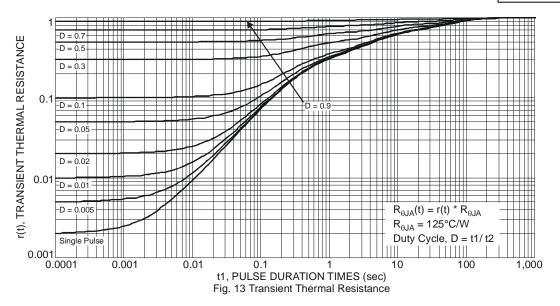






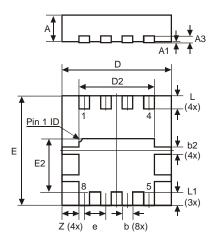






# **Package Outline Dimensions**

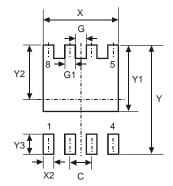
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Z	_	_	0.515		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.420			
Y	3.700			
Y1	2.250			
Y2	1.850			
Y3	0.700			
X	2.370			
X2	0.420			



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